

## Silicon Super Fast Recovery Diode

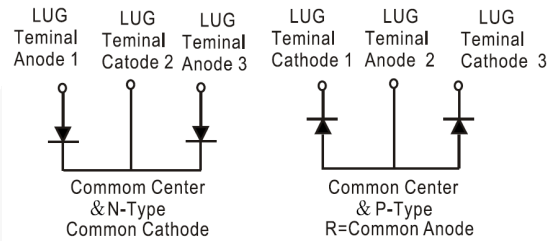
$V_{RRM} = 400\text{ V} - 600\text{ V}$

$I_{F(AV)} = 400\text{ A}$

### Features

- High Surge Capability
- Types from 400 V to 600 V  $V_{RRM}$
- Isolation Type Package
- Electrically Isolated base plate
- Not ESD Sensitive

### Three Tower Package



Maximum ratings, at  $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	MURT40040(R)	MURT40060(R)	Unit
Repetitive peak reverse voltage	$V_{RRM}$		400	600	V
RMS reverse voltage	$V_{RMS}$		283	424	V
DC blocking voltage	$V_{DC}$		400	600	V
Operating temperature	$T_j$		-55 to 150	-55 to 150	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-55 to 150	-55 to 150	$^\circ\text{C}$

Electrical characteristics, at  $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	MURT40040(R)	MURT40060(R)	Unit
Average forward current (per pkg)	$I_{F(AV)}$	$T_C = 125\text{ }^\circ\text{C}$	400	400	A
Peak forward surge current (per leg)	$I_{FSM}$	$t_p = 8.3\text{ ms}$ , half sine	3300	3300	A
Maximum instantaneous forward voltage (per leg)	$V_F$	$I_{FM} = 200\text{ A}$ , $T_j = 25\text{ }^\circ\text{C}$	1.35	1.70	V
Maximum instantaneous reverse current at rated DC blocking voltage (per leg)	$I_R$	$T_j = 25\text{ }^\circ\text{C}$	25	25	$\mu\text{A}$
		$T_j = 125\text{ }^\circ\text{C}$	3	3	mA
Maximum reverse recovery time (per leg)	$T_{rr}$	$I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{RR} = 0.25\text{ A}$	180	240	nS

### Thermal characteristics

Maximum thermal resistance, junction - case (per leg)	$R_{\theta JC}$		0.35	0.35	$^\circ\text{C/W}$
---	-----------------	--	------	------	--------------------

Figure .1- Typical Forward Characteristics

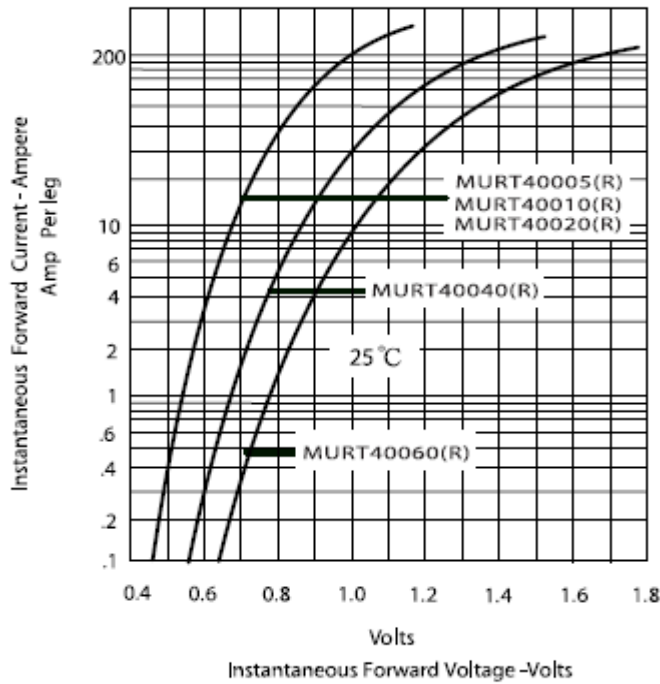


Figure .2- Forward Derating Curve

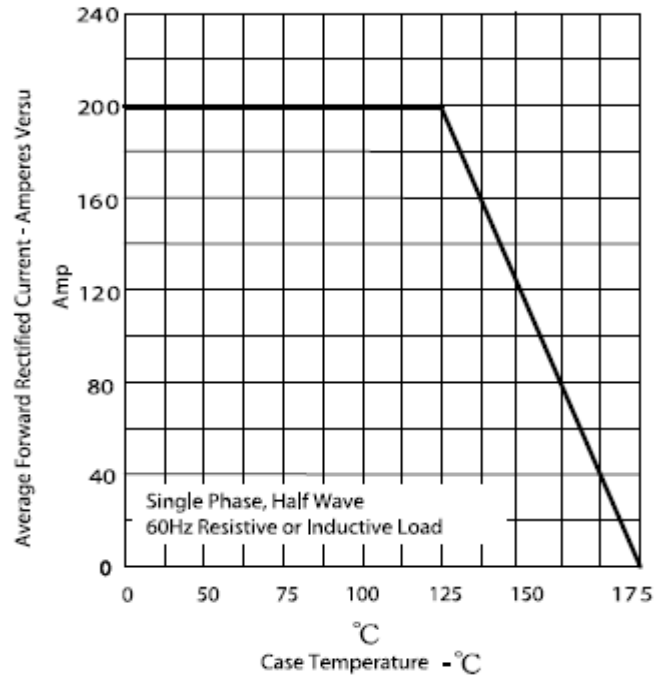


Figure.3- Peak Forward Surge Current

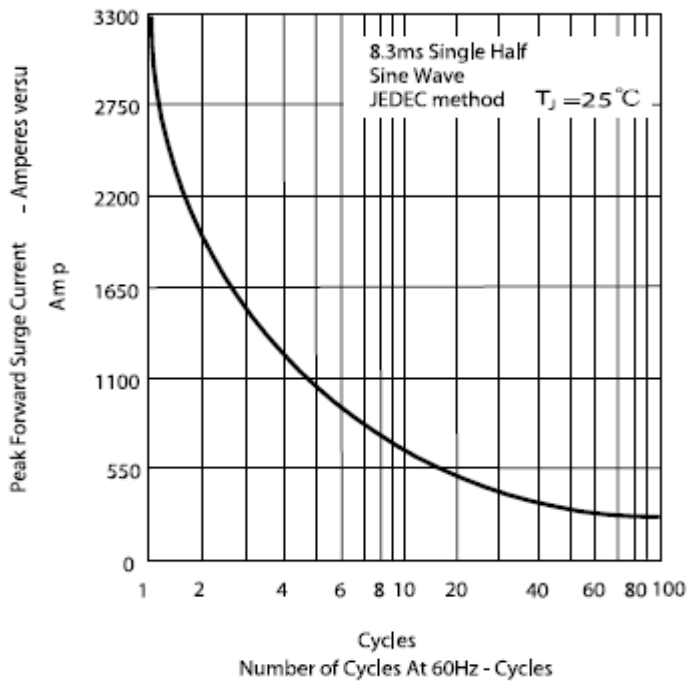
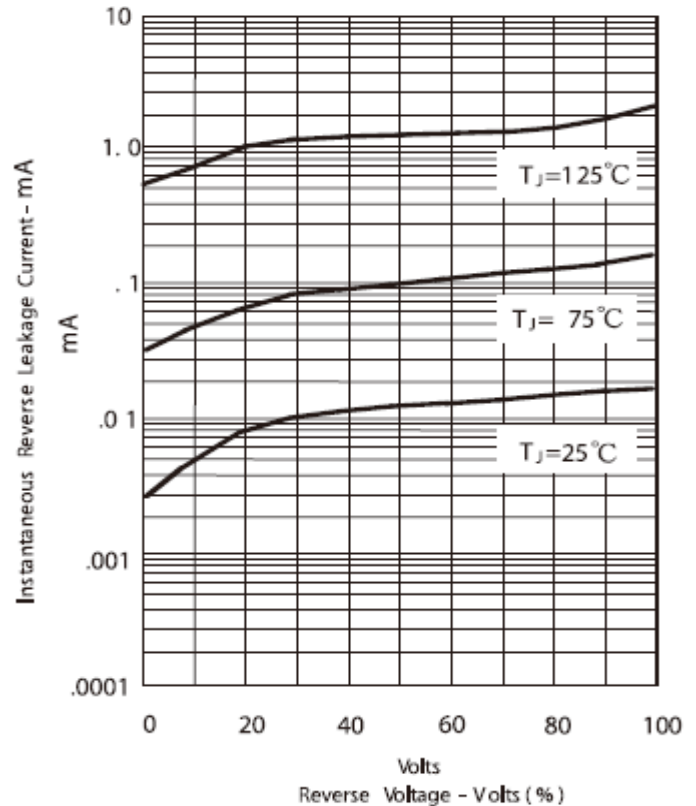
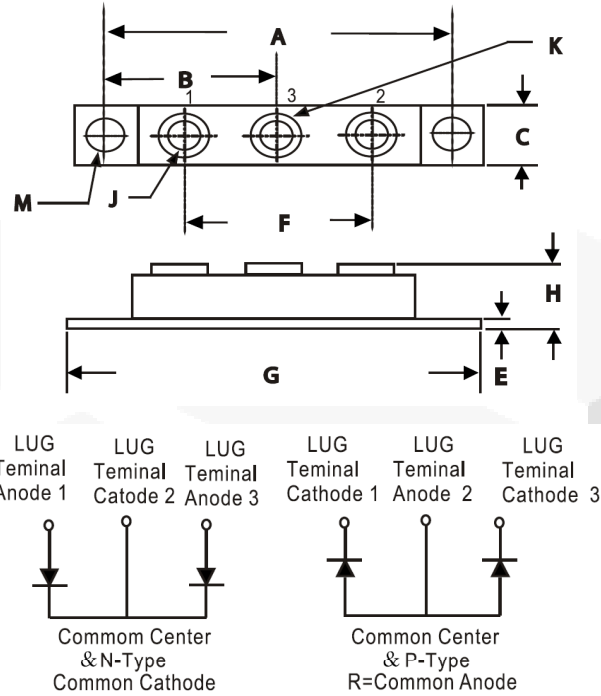


Figure .4 -Typical Reverse Characteristics



### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIM	Inches		Millimeters	
	Min	Max	Min	Max
A	3.150	NOM	80.01	NOM
B	1.565	1.585	39.75	40.26
C	.700	.800	17.78	20.32
E	.119	.132	3.02	3.35
F	1.327	REF	33.72	REF
G	3.550	3.65	90.17	92.71
H	—	.73	—	18.30
J	1/4 -20 UNC FULL			
K	.472	.511	12.00	13.00
M	.275	.295	6.99	7.49
N	2.380	2.46	60.50	62.50

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[GeneSiC Semiconductor:](#)

[MURT40060](#) [MURT40060R](#) [MURT40040R](#) [MURT40040](#)